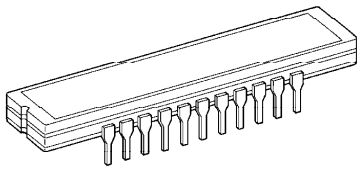
TOSHIBA CCD LINEAR IMAGE SENSOR CCD(Charge Coupled Device)

TCD1205D

The TCD1205D is a high sensitive and low dark current 2048-elements linear image sensor. The sensor can be used for POS handscanner.
The device is operated by only 5V power supply, and mounted in 22-pin cerdip package with hermetic sealed optical glass window.
The TCD1205D has electronic shutter function (ICG). Electronic shutter function can keep always output voltage constant that vary with the intensity of lights.



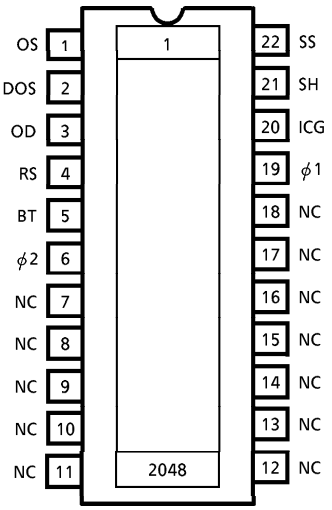
WDIP22-G-400-2.54A

Weight : 4.4g (Typ.)

FEATURES

- Number of Image Sensing Elements : 2048
- Image Sensing Element Size : 14μm by 200μm on 14μm centers
- Photo Sensing Region : High sensitive and low dark current pn photodiode
- Clock : 2 phase (5V)
- Internal Circuit : Electronic shutter function (ICG)
- Package : 22 pin cerdip

PIN CONNECTIONS



(TOP VIEW)

MAXIMUM RATINGS (Note 1)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Clock Pulse Voltage	V_ϕ	−0.3~8	V
Shift Pulse Voltage	V_{SH}		
Reset, Boost Pulse Voltage	V_{RS}, V_{BT}		
Integration Clear Gate Pulse Voltage	V_{ICG}		
Power Supply Voltage	V_{OD}		
Operating Temperature	T_{opr}	−25~60	°C
Storage Temperature	T_{stg}	−40~100	°C

(Note 1) All voltage are with respect to SS terminals (Ground).

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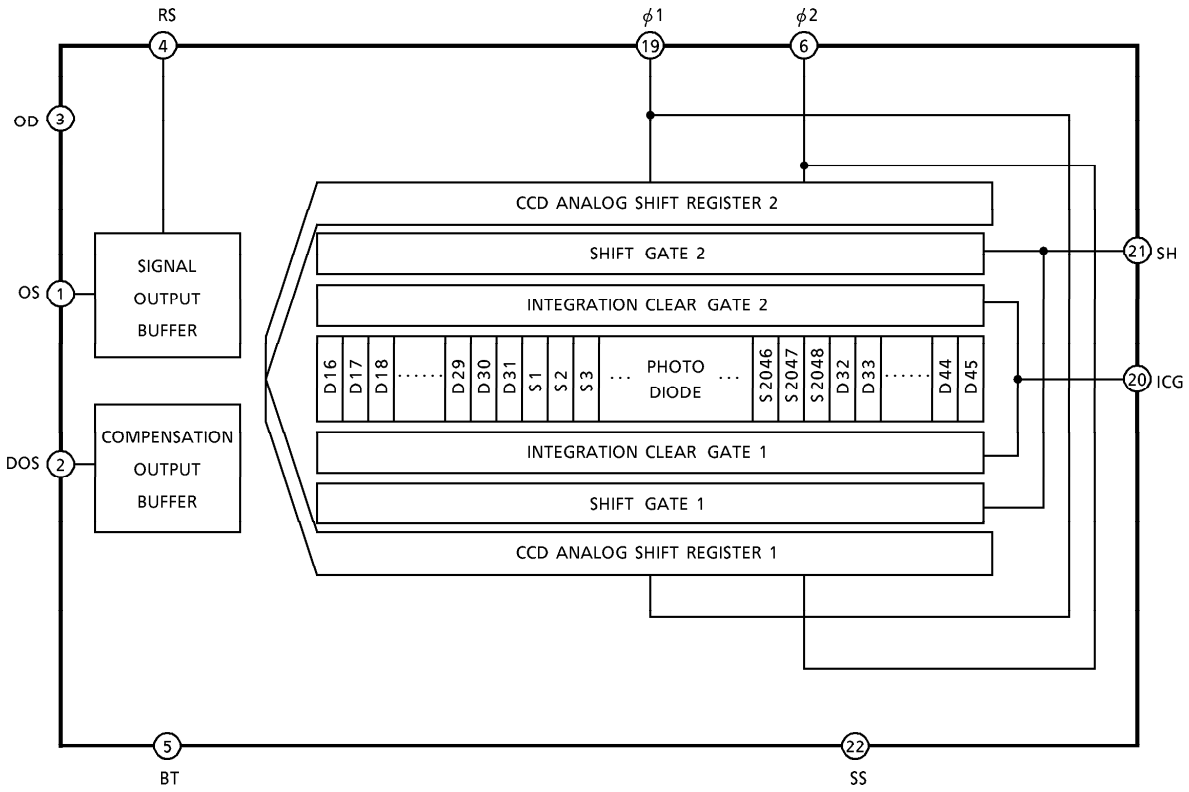
CIRCUIT DIAGRAM



PIN NAMES

$\phi 1$	Clock (Phase 1)
$\phi 2$	Clock (Phase 2)
RS	Reset Gate
SH	Shift Gate
I_{CG}	Integration Clear Gate
BT	Boost Gate
OS	Signal Output
DOS	Compensation Output
OD	Power
SS	Ground
NC	Non Connection

OPTICAL / ELECTRICAL CHARACTERISTICS

(Ta = 25°C, V_{OD} = 5V, $V_\phi = V_{SH} = V_{RS} = V_{BT}$ = 5V (Pulse), f_ϕ = 0.5MHz, f_{RS} = 1MHz, Load Resistance = 100kΩ, t_{INT} (Integration Time) = 10ms, Light Source = Daylight Fluorescent Lamp)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	NOTE
Sensitivity	R	64	80	—	V / lx·s	(Note 2)
Photo Response Non Uniformity	PRNU	—	—	10	%	(Note 3)
Saturation Output Voltage	V_{SAT}	0.55	0.8	—	V	(Note 4)
Saturation Exposure	SE	0.006	0.01	—	lx·s	(Note 5)
Dark Signal Voltage	V_{MDK}	—	2	5	mV	(Note 6)
DC Power Dissipation	PD	—	—	25	mW	
Total Transfer Efficiency	TTE	92	95	—	%	
Output Impedance	Z_o	—	0.5	1	kΩ	
Dynamic Range	DR	—	400	—	—	(Note 7)
DC Signal Output Voltage	V_{OS}	1.5	3.0	4.5	V	(Note 8)
DC Compensation Output Voltage	V_{DOS}	1.5	3.0	4.5	V	(Note 8)
DC Mismach Voltage	$\lvert V_{OS}-V_{DOS}\rvert$	—	—	200	mV	(Note 8)

(Note 2) Sensitivity for LED (660nm) is 600V / lx·s (Typ.)

(Note 3) Measured at 50% of SE (Typ.)

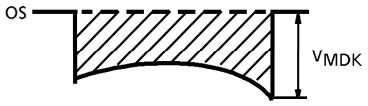
Definition of PRNU: $PRNU = \frac{\Delta\chi}{\overline{\chi}} \times 100\ (\%)$

Where $\overline{\chi}$ is average of total signal outputs and $\Delta\chi$ is the maximum deviation from $\overline{\chi}$ under uniform illumination.

(Note 4) V_{SAT} is defined as minimum saturation output voltage of all effective pixels.

(Note 5) Definition of SE : $SE = \frac{V_{SAT}}{R}$ (lx·s)

(Note 6) V_{MDK} is defined as maximum dark signal voltage of all efiective pixels.

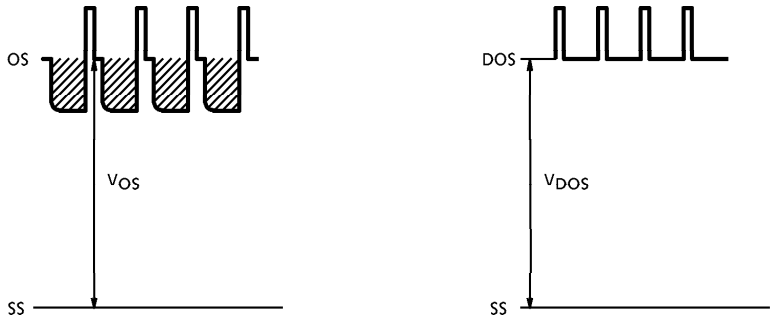


(Note 7) Definition of DR : $DR = \frac{V_{SAT}}{V_{MDK}}$

V_{MDK} is proportional to t_{INT} (Integration time).

So the shorter t_{INT} condition makes wider DR value.

(Note 8) DC signal output voltage and DC compensation output voltage are defined as follows:



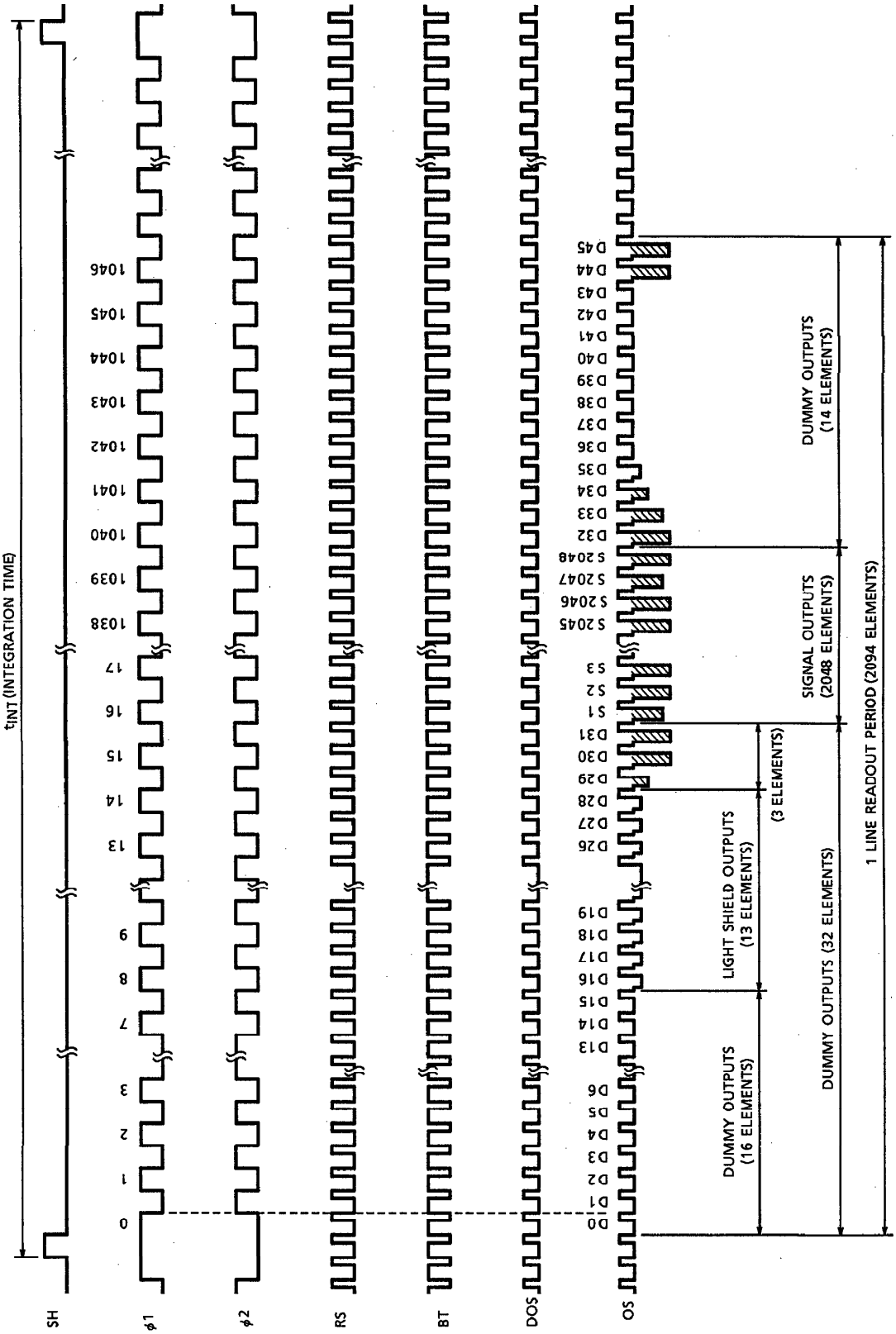
OPERATING CONDITION

CHARACTERISTIC		SYMBOL	MIN.	TYP.	MAX.	UNIT
Clock Pulse Voltage	"H" Level	V_{ϕ}	4.5	5.0	5.5	V
	"L" Level		0	0.2	0.5	
Shift Pulse Voltage	"H" Level	V_{SH}	4.5	5.0	5.5	V
	"L" Level		0	0.2	0.5	
Reset, Boost Pulse Voltage	"H" Level	V_{RS}, V_{BT}	4.5	5.0	5.5	V
	"L" Level		0	0.2	0.5	
Integration Clear Gate Voltage	"H" Level	V_{ICG}	4.5	5.0	5.5	V
	"L" Level		0	0.2	0.5	
Power Supply Voltage		V_{OD}	4.5	5.0	5.5	V

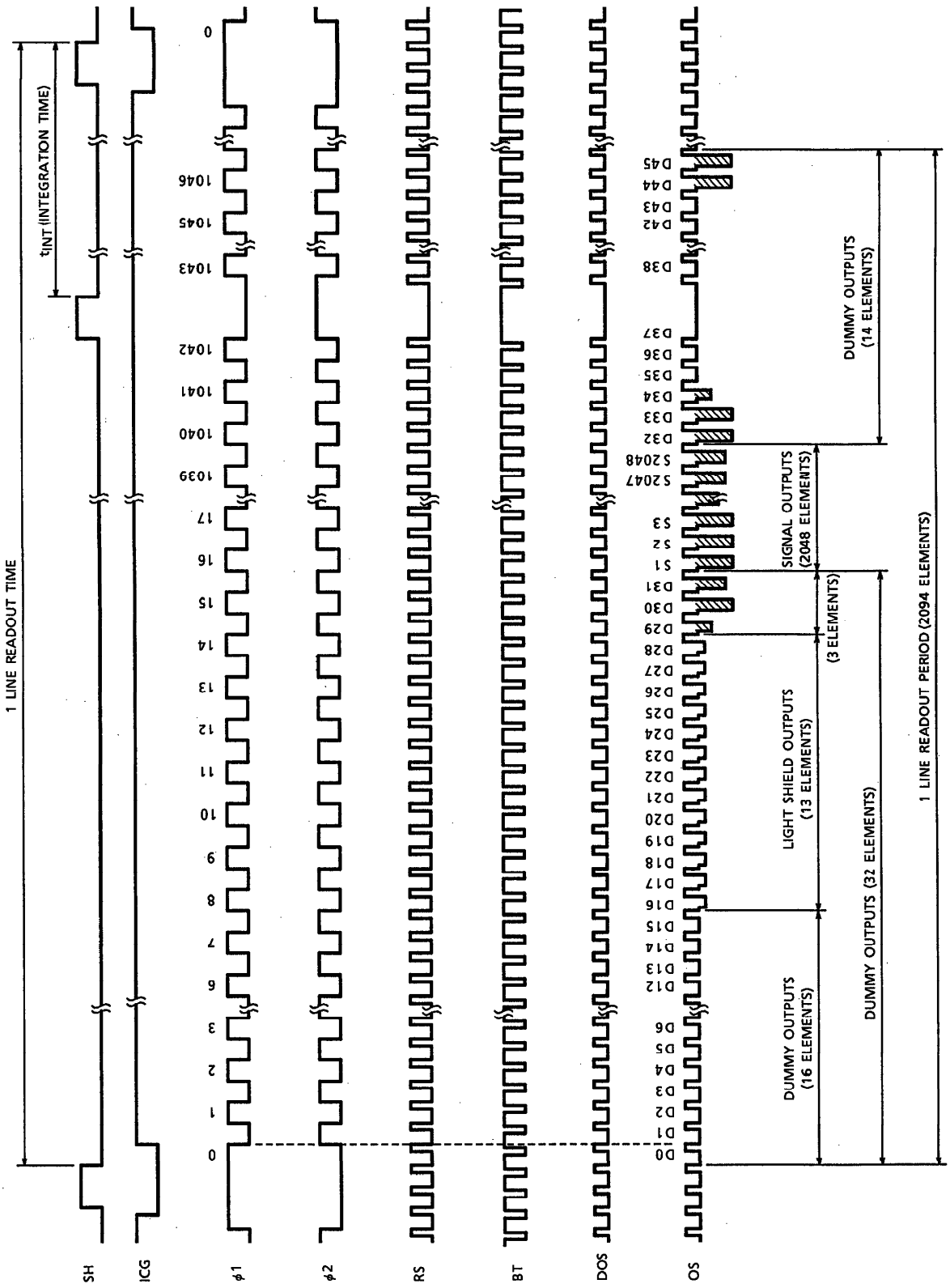
CLOCK CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Clock Pulse Frequency	f_{ϕ}	0.01	0.5	1.0	MHz
Reset Pulse Frequency	f_{RS}	0.02	1.0	2.0	MHz
Clock Capacitance	$C_{\phi A}$	—	400	500	pF
BT Gate Capacitance	C_{BT}	—	10	25	pF
Shift Gate Capacitance	C_{SH}	—	200	250	pF
Reset Gate Capacitamce	C_{RS}	—	10	25	pF
Integration Clear Gate Capacitance	C_{ICG}	—	100	200	pF

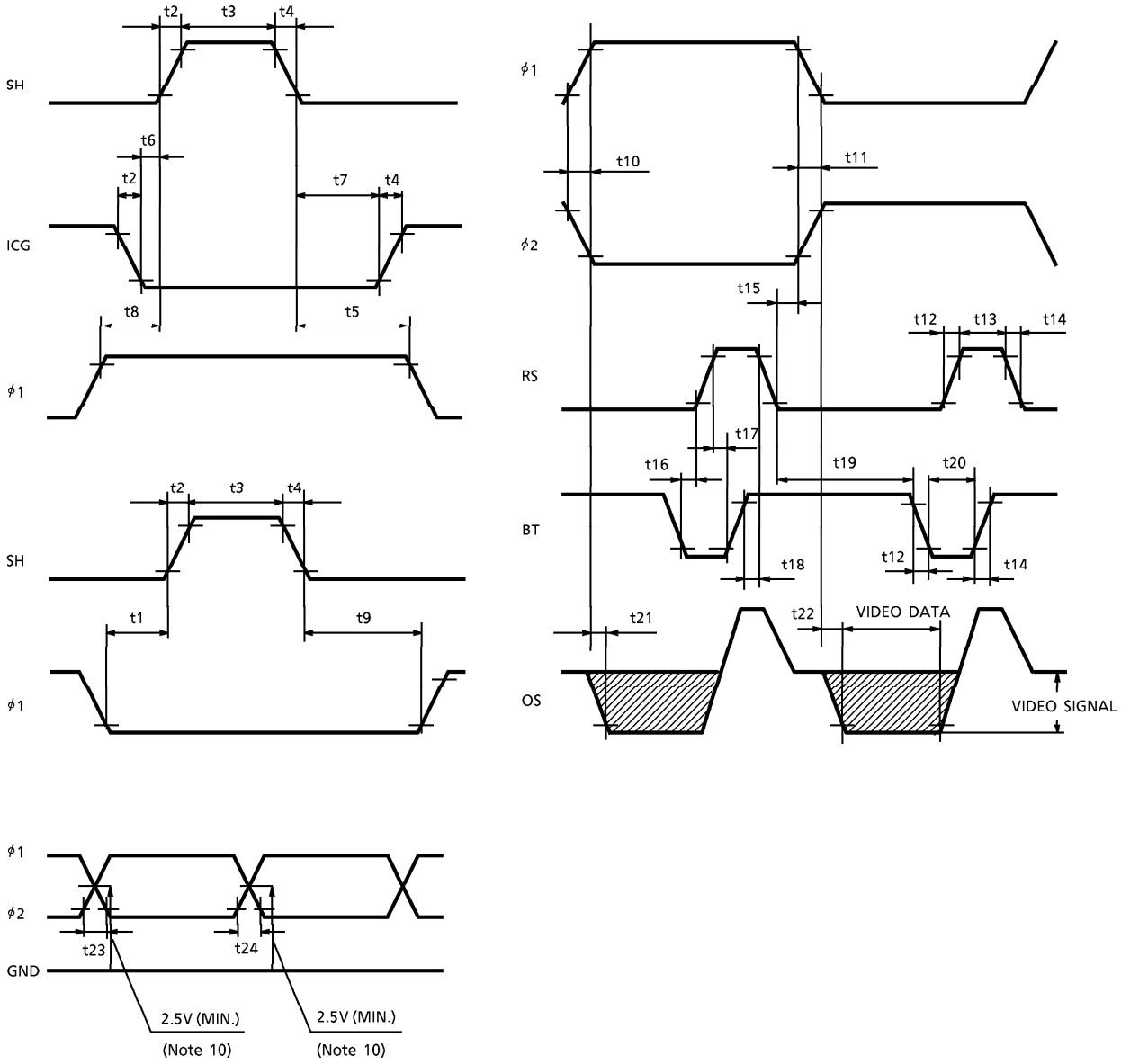
TAIMING CHART



TAIMING CHART (EXAMPLE : USE ELECTRONIC SHUTTER)



TIMING REQUIREMENS

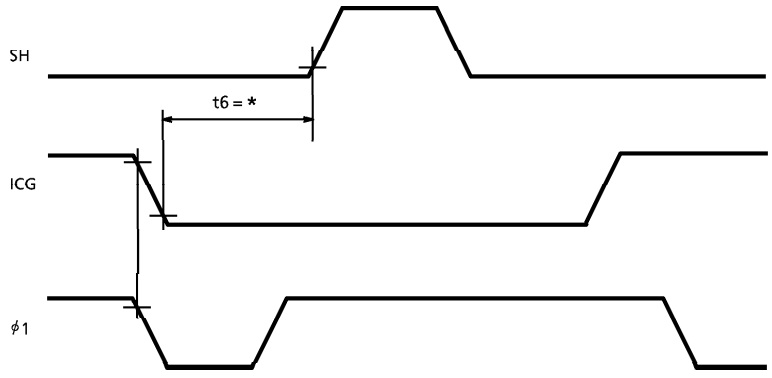


(Note 10) If $\phi 1$ & $\phi 2$ pulse cross point could't be kept over 2.5V, it should be 1.5V and t23 and t24 should be 60ns.

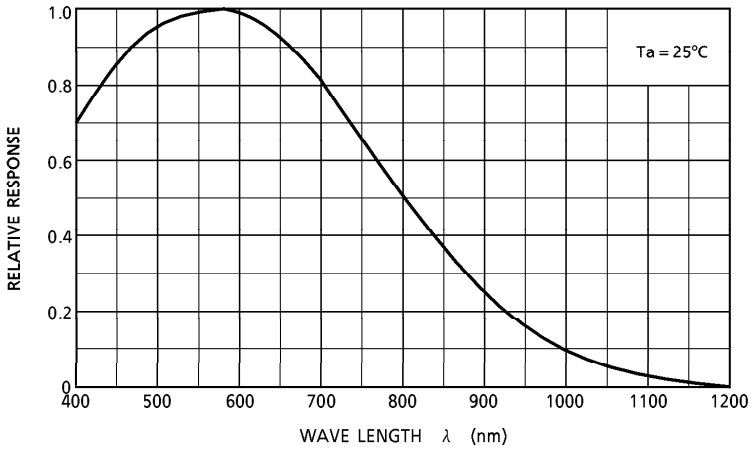
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Pulse Timing of SH & ϕ1	t1	0	100	—	ns
Pulse Timing of SH & ϕ1	t5	2000	3000	—	ns
SH, ICG Pulse Rise & Fall Time	t2, t4	0	50	—	ns
SH Pulse Width (Note 11)	t3, t3'	1000	2000	—	ns
Pulse Timing of SH & ICG	t6	50	100	*	ns
Pulse Timing of SH & ICG	t7	1000	—	t5	ns
Pulse Timing of ICG & ϕ1	t8	0	100	—	ns
Pulse Timing of ICG & ϕ1	t9	500	—	—	ns
ϕ1, ϕ2 Pulse Rise & Fall Time	t10, t11	0	60	—	ns
RS, BT Pulse Rise & Fall Time	t12, t14	0	60	—	ns
RS Pulse Width	t13	60	260	—	ns
Pulse Timing of ϕ1, ϕ2, RS	t15	20	—	—	ns
Pulse Timing of RS & BT	t16	50	100	—	ns
Pulse Timing of RS & BT	t17	20	—	—	ns
Pulse Timing of RS & BT	t18	40	—	—	ns
Pulse Timing of RS & BT	t19	200	—	—	ns
BT Pulse Width	t20	70	250	—	ns
Video Data Delay Time	t21, t22	—	80	—	ns

(Note 11) Have to use t3 = t3'

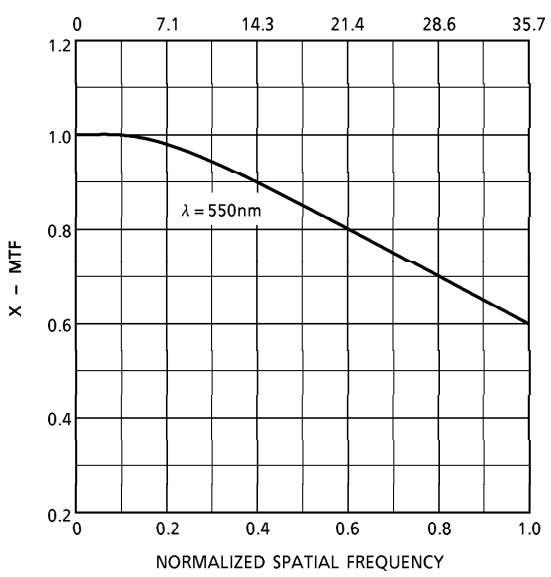
* t6 = MAXIMUM TIMING



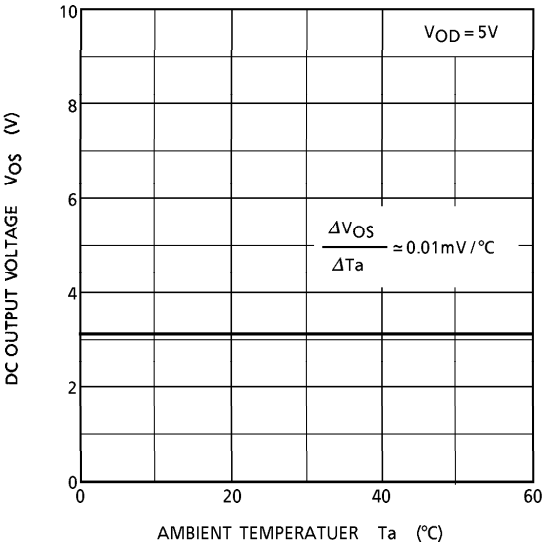
SPECTRAL RESPONSE



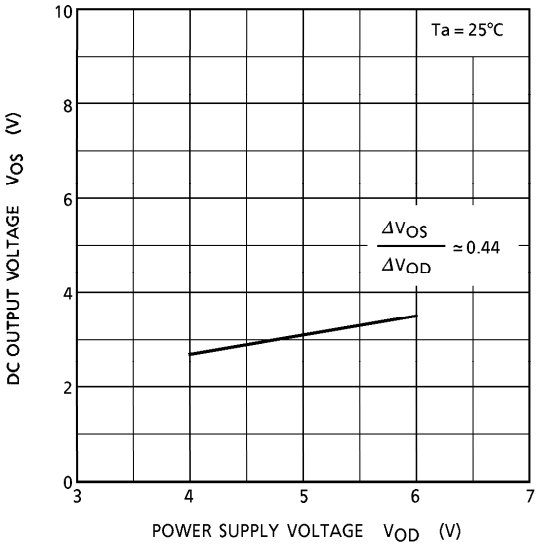
MODULATION TRANSFER FUNCTION
OF X-DIRECTION



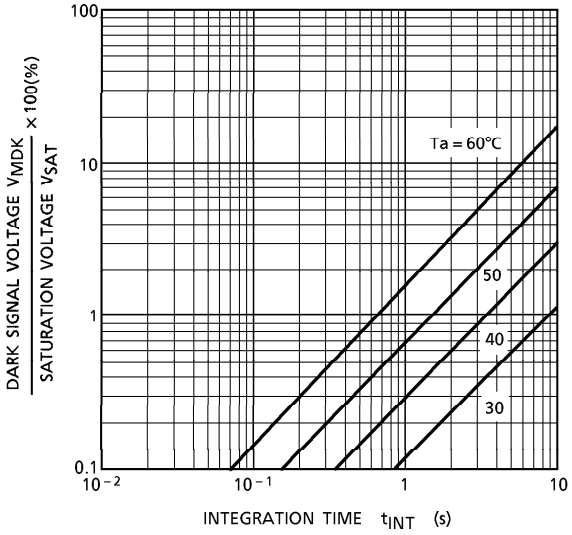
DC OUTPUT VOLTAGE – AMBIENT TEMPERATUER



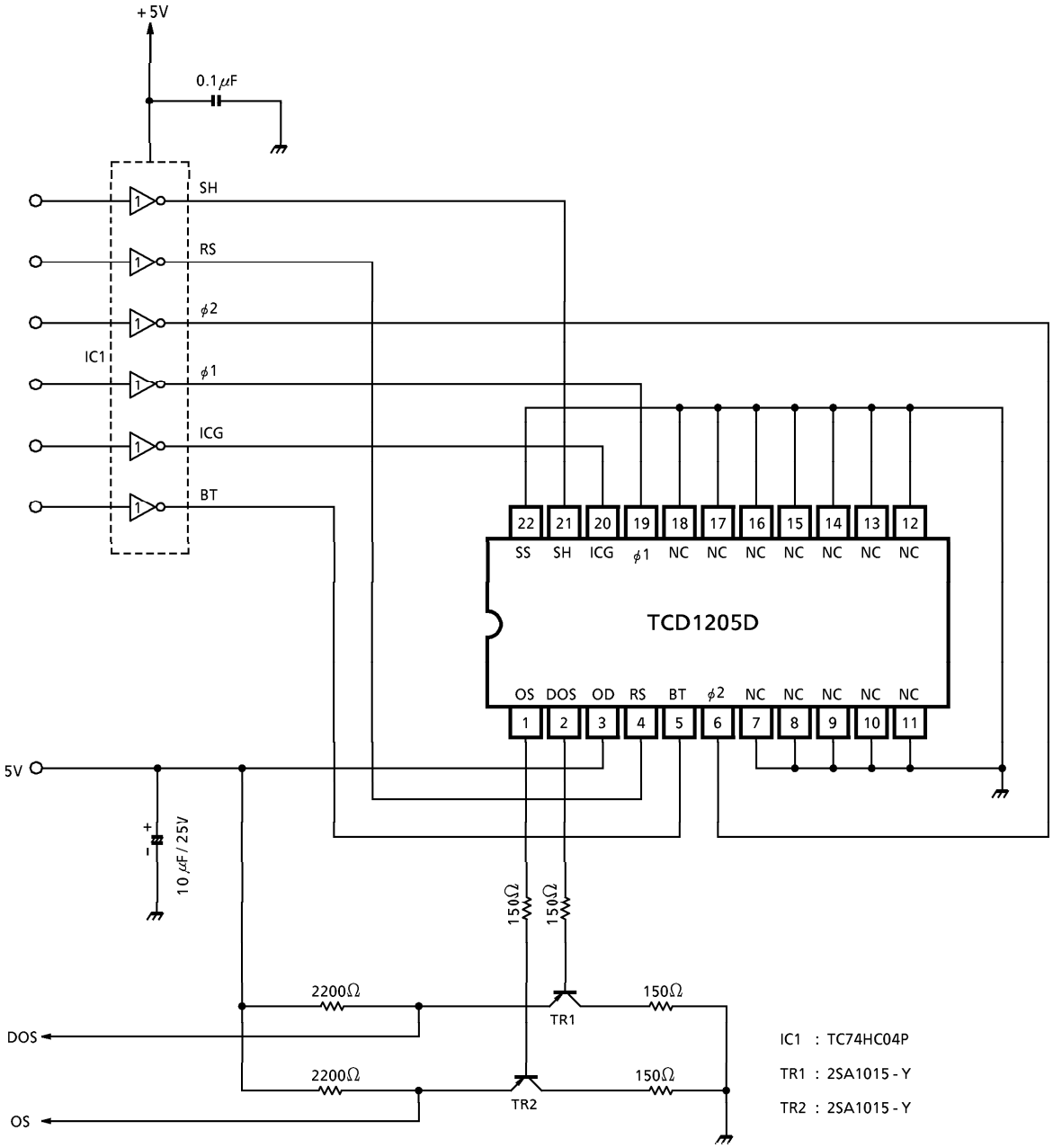
DC OUTPUT VOLTAGE – POWER SUPPLY VOLTAGE



DARK SIGNAL VOLTAGE – INTEGRATION TIME



TYPICAL DRIVE CIRCUIT



CAUTION

1. Window Glass

   The dust and stain on the glass window of the package degrade optical performance of CCD sensor.
   Keep the glass window clean by saturating a cotton swab in alcohol and lightly wiping the surface, and allow the glass to dry, by blowing with filtered dry N_2.
   Care should be taken to avoid mechanical or thermal shock because the glass window is easily to damage.

2. Electrostatic Breakdown

   Store in shorting clip or in conductive foam to avoid electrostatic breakdown.

3. Incident Light

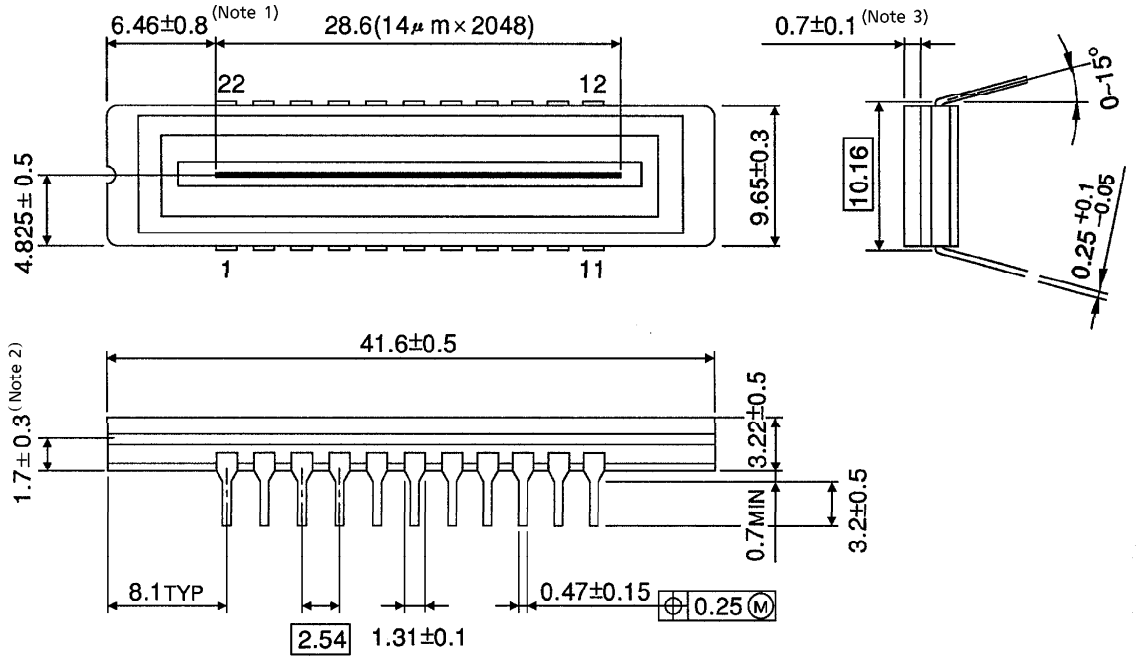
   CCD sensor is sensitive to infrared light.
   Note that infrared light component degrades resolution and PRNU of CCD sensor.

4. Lead Frame Forming

   Since this package is not stout against mechanical stress, you should not reform the lead frame.
   We recommend to use a IC-inserter when you assemble to PCB.

OUTLINE DRAWING

WDIP22-G-400-2.54A (D) Unit : mm



(Note 1) No. 1 SENSOR ELEMENT (S1) TO EDGE OF PACKAGE.
(Note 2) TOP OF CHIP TO BOTTOM OF PACKAGE.
(Note 3) GLASS THICKNES (n = 1.5)

Weight : 4.4g (Typ.)